

AM/FM PLL Frequency Synthesizer



Overview

The LC72130 and LC72130M are PLL frequency synthesizers for use in tuners in radio cassette recorders and other products.

Applications

PLL frequency synthesizer

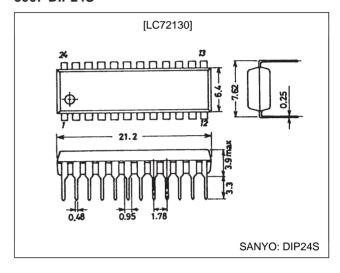
Functions

- · High-speed programmable dividers
 - FMIN: 10 to 160 MHzpulse swallower (built-in divide-by-two prescaler)
 - Alla mulas surallouser
 - AMIN: 2 to 40 MHzpulse swallower 0.5 to 10 MHzdirect division
- · IF counter
 - IFIN: 0.4 to 12 MHzAM/FM IF counter
- Reference frequencies
 - Twelve selectable frequencies (4.5 or 7.2 MHz crystal)
 - 1, 3, 5, 9, 10, 3.125, 6.25, 12.5, 15, 25, 50 and 100 kHz
- Phase comparator
 - Dead zone control
 - Unlock detection
 - Deadlock clear circuit
- Built-in MOS transistor for implementing an active lowpass filter (two systems)
- · Inputs and outputs
 - Dedicated output ports: five pins
 - Input or output ports: two pins
 - Clock time base output available
- Serial data I/O
 - Supports CCB format communication with the system controller.
- · Operating ranges
 - Supply voltage......4.5 to 5.5 V
 - Operating temperature.....-40 to +85°C
- Packages
 - DIP24S, MFP24S
 - CCB is a trademark of SANYO ELECTRIC CO., LTD.
 - CCB is SANYO's original bus format and all the bus addresses are controlled by SANYO.

Package Dimensions

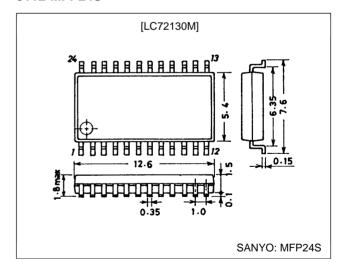
unit: mm

3067-DIP24S

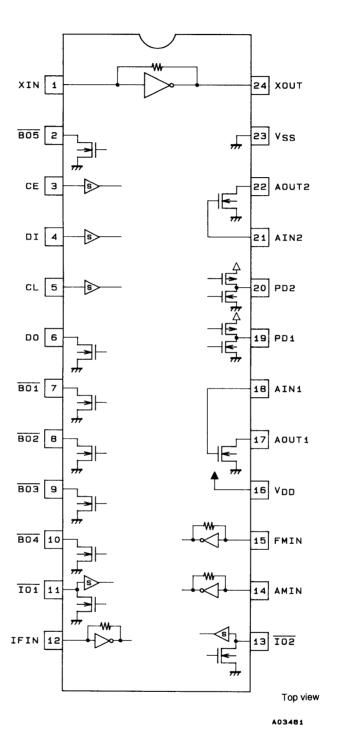


unit: mm

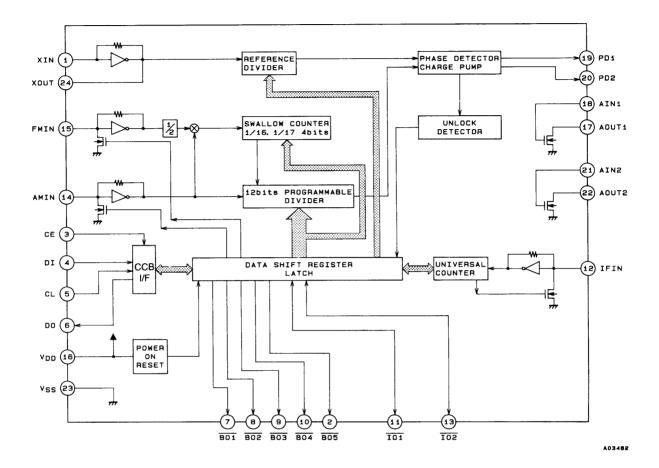
3112-MFP24S



Pin Assignment



Block Diagram



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$, $V_{SS} = 0$ V

Parameter	Symbol	Pins	Ratings	Unit
Maximum supply voltage	V _{DD} max	V _{DD}	-0.3 to +7.0	V
	V _{IN} 1 max	CE, CL, DI, AIN1, AIN2	-0.3 to +7.0	V
Maximum input voltage	V _{IN} 2 max	XIN, FMIN, AMIN, IFIN	-0.3 to V _{DD} + 0.3	V
	V _{IN} 3 max	<u>101</u> , <u>102</u>	-0.3 to +15	V
	V _O 1 max	DO	-0.3 to +7.0	V
Maximum output voltage	V _O 2 max	XOUT, PD1, PD2	-0.3 to V _{DD} + 0.3	V
	V _O 3 max	BO1 to BO5, IO1, IO2, AOUT1, AOUT2	-0.3 to +15	V
	I _O 1 max	BO1	0 to 3.0	mA
Maximum output current	I _O 2 max	DO, AOUT1, AOUT2	0 to 6.0	mA
	I _O 3 max	BO2 to BO5, IO1, IO2	0 to 10.0	mA
Allowable power dissipation	Pd max	Ta ≤ 85°C	DIP24S: 350 MFP24S: 200	mW
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

Parameter	Symbol	Pins	Conditions	min	typ	max	Unit
Supply voltage	V _{DD}	V _{DD}		4.5		5.5	V
Input high level voltage	V _{IH} 1	CE, CL, DI		0.7 V _{DD}		6.5	V
input night level voltage	V _{IH} 2	IO1, IO2		0.7 V _{DD}		13	V
Input low level voltage	V _{IL}	CE, CL, DI, $\overline{\text{IO1}}$, $\overline{\text{IO2}}$		0		0.3 V _{DD}	V
	V _O 1	DO		0		6.5	V
Output voltage	V _O 2	BO1 to BO5, IO1, IO2, AOUT1, AOUT2		0		13	V
	f _{IN} 1	XIN	V _{IN} 1	1		8	MHz
	f _{IN} 2	FMIN	V _{IN} 2	10		160	MHz
Input frequency	f _{IN} 3	AMIN	V _{IN} 3, SNS = 1	2		40	MHz
	f _{IN} 4	AMIN	$V_{IN}4$, SNS = 0	0.5		10	MHz
	f _{IN} 5	IFIN	V _{IN} 5	0.4		12	MHz
	V _{IN} 1	XIN	f _{IN} 1	400		1500	mVrms
	V _{IN} 2-1	FMIN	f = 10 to 130 MHz	40		1500	mVrms
	V _{IN} 2-2	FMIN	f = 130 to 160 MHz	70		1500	mVrms
Input amplitude	V _{IN} 3	AMIN	f _{IN} 3 , SNS = 1	40		1500	mVrms
	V _{IN} 4	AMIN	f _{IN} 4 , SNS = 0	40		1500	mVrms
	V _{IN} 5	IFIN	f _{IN} 5, IFS = 1	40		1500	mVrms
	V _{IN} 6	IFIN	f _{IN} 6, IFS = 0	70		1500	mVrms
Oscillation-guaranteed crystal resonator	Xtal	XIN, XOUT	*	4.0		8.0	MHz

Allowable Operating Ranges at $Ta = -40 \ to \ +85^{\circ}C, \ V_{SS} = 0 \ V$

Note: * Recommended crystal oscillator CI values:

 $CI \le 120\Omega$ (For a 4.5 MHz crystal)

 $CI \le 70\Omega$ (For a 7.2 MHz crystal)

However, since the oscillator circuit characteristics depend on the printed circuit board and component values actually used, we recommend requesting a circuit evaluation from the manufacturer of the crystal used.

<Sample Ocsillator Circuit>

Crystal oscillator: HC-49/U (manufactured by Kinseki, Ltd.), CL = 12 pF

C1 = C2 = 15 pF

The circuit constants for the crystal oscillator circuit depend on the crystal used, the printed circuit board pattern, and other items. Therefore we recommend consulting with the manufacturer of the crystal for evaluation and reliability.

Electrical Characteristics at $Ta = -40~to~+85^{\circ}C,\,V_{SS} = 0~V$

Parameter	Symbol	Pins	Conditions	min	typ	max	Unit
	Rf1	XIN			1.0		MΩ
	Rf2	FMIN			500		kΩ
Built-in feedback resistance	Rf3	AMIN			500		kΩ
	Rf4	IFIN			250		kΩ
	Rpd1	FMIN			200		kΩ
Built-in pull-down resistor	Rpd2	AMIN			200		kΩ
Hysteresis	V _{HIS}	CE, CL, DI, IO1, IO2			0.1 V _{DD}		V
Output high level voltage	V _{OH} 1	PD1, PD2	IO = -1 mA	V _{DD} – 1.0	55		V
	V _{OL} 1	PD1, PD2	IO = 1 mA			1.0	V
			IO = 0.5 mA			0.5	V
	V _{OL} 2	BO1	IO = 1 mA			1.0	V
			IO = 1 mA			0.2	V
Output low level voltage	V _{OL} 3	DO	IO = 5 mA			1.0	V
			IO = 1 mA			0.2	V
	V _{OL} 4	BO2 to BO5, IO1, IO2	IO = 5 mA			1.0	V
		-, -, -, -	IO = 8 mA			1.6	V
	V _{OL} 5	AOUT1, AOUT2	IO = 1 mA, AIN = 1.3 V			0.5	V
	I _{IH} 1	CE, CL, DI	V _I = 6.5 V			5.0	V
	I _{IH} 2	101, 102	V _I = 13 V			5.0	μA
Input high level current	I _{IH} 3	XIN	$V_I = V_{DD}$	2.0		11	μA
	I _{IH} 4	FMIN, AMIN	$V_I = V_{DD}$	4.0		22	μA
	I _{IH} 5	IFIN	$V_I = V_{DD}$	8.0		44	μA
	I _{IH} 6	AIN1, AIN2	V _I = 6.5 V			200	nA
	I _{IL} 1	CE, CL, DI	V _I = 0 V			5.0	μA
	I _{IL} 2	101, 102	V _I = 0 V			5.0	μA
	I _{IL} 3	XIN	V _I = 0 V	2.0		11	μA
Input low level current	I _{IL} 4	FMIN, AMIN	V _I = 0 V	4.0		22	μA
	I _{IL} 5	IFIN	V _I = 0 V	8.0		44	μA
	I _{IL} 6	AIN1, AIN2	V _I = 0 V			200	nA
Output off lookage ourrent	I _{OFF} 1	BO1 to BO5, AOUT1, AOUT2, IO1, IO2	V _O = 13 V			5.0	μA
Output off leakage current	I _{OFF} 2	DO	V _O = 6.5 V			5.0	μA
High level three-state off leakage current	I _{OFFH}	PD1, PD2,	$V_O = V_{DD}$		0.01	200	nA
Low level three-state off leakage current	I _{OFFL}	PD1, PD2	V _O = 0 V		0.01	200	nA
Input capacitance	C _{IN}	FMIN			6		pF
	I _{DD} 1	V _{DD}	Xtal = 7.2 MHz, f _{IN} 2 = 130 MHz, V _{IN} 2-1= 40 mVrms		5	10	mA
Current drain	I _{DD} 2	V_{DD}	PLL block stopped (PLL INHIBIT), Xtal oscillator operating (Xtal = 7.2 MHz)		0.5		mA
	I _{DD} 3	V _{DD}	PLL block stopped Xtal oscillator stopped			10	μА

Pin Functions

Symbol	Pin No.	Туре	Functions	Circuit configuration
XIN XOUT	1 24	X'tal OSC	Crystal resonator connection (4.5/7.2 MHz)	A02598
FMIN	15	Local oscillator signal input	Serial data input: FMIN is selected when DVS is set to 1. The input frequency range is from 10 to 160 MHz. The signal is passed through a built-in divide-by-two prescaler and then supplied to the swallow counter. Although the range of divisor settings is from 272 to 65,535, the actual divisor is twice the setting since there is also a built-in divide-by-two prescaler.	A02599
AMIN	14	Local oscillator signal input	Serial data input: AMIN is selected when DVS is set to 0. Serial data input: When SNS is set to 1: The input frequency range is from 2 to 40 MHz. The signal is supplied directly to the swallow counter. The range of divisor settings is from 272 to 65,535 and the actual divisor will be the value set. Serial data input: When SNS is set to 0: The input frequency range is from 0.5 to 10 MHz. The signal is supplied directly to a 12-bit programmable divider. The range of divisor settings is from 4 to 4,095 and the actual divisor will be the value set.	A02599
CE	3	Chip enable	Must be set high when serial data is input to the LC72130 (DI), or when serial data is output (DO).	A02600
CL	5	Clock	Used as the synchronization clock when serial data is input to the LC72130 (DI), or when serial data is output (DO).	□ S A02600
DI	4	Data input	Inputs serial data sent from the controller to the LC72130.	A02600
DO	6	Data output	Outputs serial data sent from the LC72130 to the controller. The content of the output data is determined by the serial data DOC0 to DOC2.	A02501
V _{DD}	16	Power supply	The LC72130 power supply (V _{DD} = 4.5 to 5.5 V) The power on reset circuit operates when power is first applied.	-

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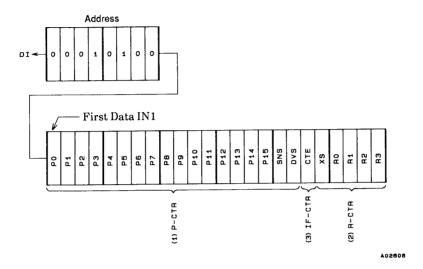
Symbol	Pin No.	Туре	Functions	Circuit configuration
V _{SS}	23	Ground	The LC72130 ground	_
BO1 BO2 BO3 BO4 BO5	7 8 9 10 2	Output port	Dedicated output pins The output states are determined by BO1 to BO5 in the serial data. Data: 0 = open, 1 = low These pins go to the open state after the power on reset. An 8 Hz time base signal can be output from BO1 when TBC in the serial data is set to 1. Note that the ON impedance of the BO1 pin is higher than that of the other pins (BO2 to BO5).	A02601
IO1 IO2	11 13	I/O port	 Pins used for both input and output The input or output state is determined by bits IOC1 and IOC2 in the serial data. Data: 0 = input port, 1 = output port When specified for use as an input port: The input state is transmitted to the controller through the DO pin. Input state: Low → data value = 0 High → data value = 1 When specified for use as an output port: The output state is determined by bits IO1 and IO2 in the serial data. Data: 0 = open, 1 = low These pins go to the input port state after the power ON reset. 	A02602
PD1 PD2	19 20	Charge pump output	PLL charge pump output When the frequency generated by dividing the local oscillator frequency by N is higher than the reference frequency, a high level will be output from the PD pin. Similarly, when that frequency is lower, a low level will be output. The PD pin goes to the high impedance state when the frequencies agree.	A02503
AIN1 AOUT1 AIN2 AOUT2	18 17 21 22	LPF amplifier transistor	The MOS transistor used for the PLL active low-pass filter.	A02604
IFIN	12	IF counter	The input frequency range is from 0.4 to 12 MHz. The signal is supplied directly to the IF counter. The result from the IF counter MSB is output through the DO pin. There are four measurement periods: 4, 8, 32, or 64 ms.	A02599

Serial Data I/O Methods

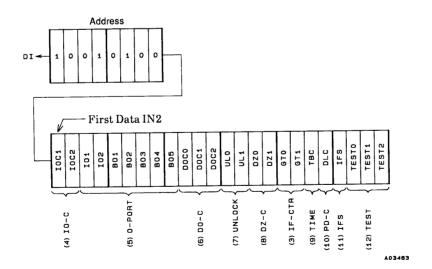
The LC72130 uses Sanyo's audio LSI serial bus format, the CCB (computer control bus) format, for data I/O. This LSI adopts an 8-bit address version of the CCB format.

	I/O mode					Iress				Function		
	o mode	B0	B1	B2	В3	A0	A1	A2	A3	. 310001		
1	IN1 (82)	0	0	0	1	0	1	0	0	This is a control data input (serial data input) mode. 24 bits of data are input. See the "DI Control Data (Serial Data Input)" item for a description of the contents of the input data.		
2	IN2 (92)	1	0	0	1	0	1	0	0	This is a control data input (serial data input) mode. data are input. See the "DI Control Data (Serial Data Input)" item for a description of the contents of the input data.		
3	OUT (A2)	0	1	0	1	0	1	0	0	This is a data output (serial data output) mode. The number of bits output is equal to the number of cloc cycles. See the "DO Control Data (Serial Data Output)" item for description of the content of the output data.		
	CL (3) DI BO		\ B	2	B3 \	AO	A1			A3 First Data IN1/2 First Data OUT		

- 1. DI Control Data (Serial Data Input)
 - IN1 Mode



• IN2 Mode



2. DI Control Data Functions

No.	Control block/data		Related data						
	Programmable divider data	Sets the p	Sets the programmable divider divisor.						
	P0 to P15	This value							
		dependin	g on DVS a	and SNS.	(*: don't d	are)			
		DVS	SNS	LSB	Divisor	setting (N)	Actual divisor		
		1	*	P0	272 t	o 65535	Twice the value of the setting		
		0	1	P0	272 t	o 65535	The value of the setting		
(4)		0	0	P4		to 4095	The value of the setting		
(1)	DVC CNC		to P3 are	•					
	DVS, SNS				ignal input pin for the programmable divider and switch the input don't care)				
		DVS	SNS	Input	pin	ļ	nput frequency range		
		1	*	FMI	N		10 to 160 MHz		
		0	1	AMI	N		2 to 40 MHz		
		0	0	AMI			0.5 to 10 MHz		
	Defense a divides dete					tem for more in	nformation.		
	Reference divider data R0 to R3	Selects th		•					
	, , , , , , , , , , , , , , , , , , ,	R3	R2	R1	R0	Re	ference frequency (kHz)		
		0 0	0	0 0	0		100 50		
			0	1	Ö		25		
		0	0	1	1		25		
		0 0	1	0 0	0		12.5 6.25		
		0	1	1	0		3.125		
		0	1	1	1		3.125		
		1 1	0	0 0	0		10 9		
(2)		1	0	1	0		5		
(2)		1	0	1	1		1		
		1 1	1	0 0	0		3 15		
		1	1	1	0	PLL I	NHIBIT + X'tal OSC STOP		
		1	1	1	1		PLL INHIBIT		
		Note: PL							
							block are stopped, the FMIN, (ground), and the charge pump		
			to the hig	•		Juli-uowii State	(ground), and the charge pump		
	XS	Crystal re	sonator se	lection					
		XS = 0: 4 XS = 1: 7							
				ncy is sele	ected after	the power ON	reset.		
	IF counter control data	IF counte	r measurei	ment start	data				
	CTE	_	Counter st Counter re						
	GT0, GT1	• Determine			asuremen	t period.			
	•		ı				Mait time (ma)	IFS	
(3)		GT1 0	GT0 0	iviea	surement t	ume (ms)	Wait time (ms) 3 to 4		
		0	1		8		3 to 4		
		1	0		32		7 to 8		
		1	1		64		7 to 8		
				ounter" ite		e information.			
(4)	I/O port specification data					tional pins IO1	and IO2.		
<u> </u>	Output port data		input mod	· · · · ·		RO1 to POF	IO1 and IO2 output ports		
(5)	Output port data BO1 to BO5, IO1, IO2		open, 1 =		ut 110111 the	; DO 1 10 DO5,	10 1 anu 102 output ports	IOC1	
			•		elected aft	er the power O	N reset.	IOC2	
	•							•	

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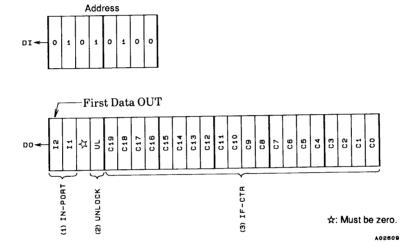
No.	Control block/data				Functions		Related data
	DO pin control data	Data that	determine				
	DOC0, DOC1, DOC2	DOC2	DOC1	DOC0		OO pin state	
		0	0	0	Open	o pin state	
			0	1	Low when the unlock s	state is detected	
		0	1	0	end-UC*1		
		0	1	1	Open		
		1 1	0	0	Open The IO1 pin state*2		
			1	Ö	The IO2 pin state*2		
		1	1	1	Open		
		The open	ctato ic co	alacted of	er the power ON reset.		
					IF counter measurement	completion	
l					((UL0, UL1,
(6)		DO	pin	X))	\ ((CTE, IOC1, IOC2
						, ,	
			1	Counter s	tart	② Counter ③ CE: high complete	
			@ 14#			A02608	
						started (i.e., when CTE is changed ally goes to the open state.	
			② When t	he IF cou	nter measurement comple	etes, the DO pin goes low to indicate	
			the me	ne DO pin goes to the open state.			
		2.	Goes to th				
	Also, the DO pin during a data output period (an OUT mode period with CE high) will output the contents of the internal DO serial data in synchronization with the						
						O control data (DOC0 to DOC2).	
	Unlock detection data UL0, UL1	1		. ,	detection width for checking specified detection widt	ing PLL lock. h is seen as an unlocked state.	
	,				<u> </u>		
		UL1 0	UL0 0		E detection width	Detector output	5000
(7)		0	1	Stopped 0		Open ØE is output directly	DOC0, DOC1,
		1	0	±0.55 µs	<u> </u>	øE is extended by 1 to 2 ms	DOC2
		1	1	±1.11 µs		øE is extended by 1 to 2 ms	
		Note: In t	he unlock			he UL bit in the serial data	
			comes zer				
	Phase comparator control data	Controls t	ne phase	comparate	or dead zone.		
	DZ0, DZ1	DZ1	DZ0		Dead zo	ne mode	
		0	0	DZA			
(8)		0	1	DZB			
		1	0	DZC			
		1	1	DZD			
		Dead zon	e widths: I	DZA < DZ	B < DZC < DZD		
(0)	Clock time base					me base signal to be output	PO4
(9)	TBC				is invalid in this mode.)		BO1
	Charge pump control data DLC	• Forcibly c	ontrols the	charge p	oump output.		
		D	LC		Charge pu	ımp output	
(4.0)			0	Normal of	operation		
(10)			1	Forced I			
						e (Vtune) going to zero and the VCO forcing the charge pump output to	
					to V_{CC} . (This is the deadl		
						<u> </u>	

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No.	Control block/data	Functions	Related data
(11)	IF counter control data	Note that if this value is set to zero the system enters input sensitivity degradation mode, and the sensitivity is reduced to 10 to 30 mV rms. * See the "IF Counter Operation" item for details.	
(12)	LSI test data TEST 0 to TEST2	LSI test data TEST0 TEST1 TEST2 These values must all be set to 0. TEST2 These test data are set to 0 automatically after the power ON reset.	

3. DO Output Data (Serial Data Output)

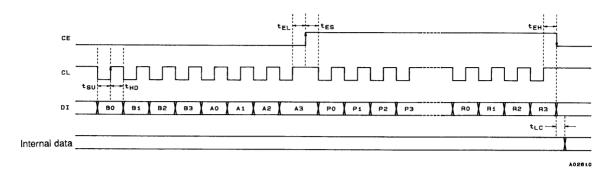
• OUT Mode



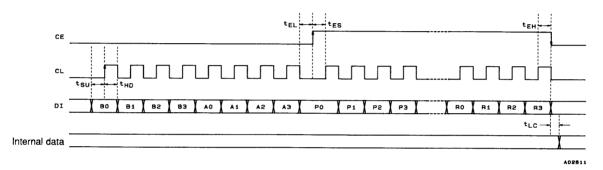
4. DO Output Data

No.	Control block/data	Functions	Related data
(1)	I/O port data I2, I1	Latched from the pin states of the TO1 and TO2 I/O ports. These values follow the pin states regardless of the input or output setting. Data is latched at the point where the circuit enters data output mode (OUT mode) I1 ← TO1 pin state	IOC1, IOC2
(2)	PLL unlock data UL	Latched from the state of the unlock detection circuit. UL ← 0: Unlocked UL ← 1: Locked or detection stopped mode	ULO, UL1
(3)	IF counter binary data C19 to C0	Latched from the value of the IF counter (20-bit binary counter). C19 ← MSB of the binary counter C0 ← LSB of the binary counter	CTE, GT0, GT1

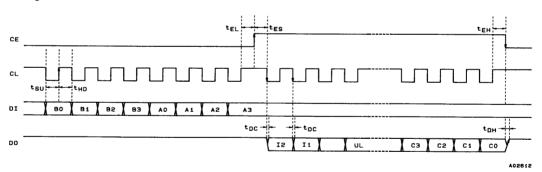
- 5. Serial Data Input (IN1/IN2) t_{SU} , t_{HD} , t_{EL} , t_{ES} , $t_{EH} \ge 0.75~\mu s$, $t_{LC} \le 0.75~\mu s$
 - ① CL: Normal high



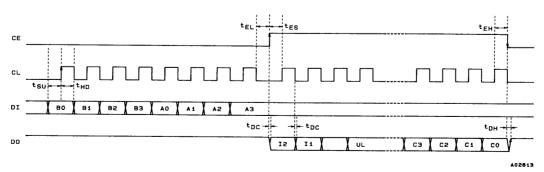
@ CL: Normal low



- 6. Serial Data Output (OUT) t_{SU} , t_{HD} , t_{EL} , t_{ES} , $t_{EH} \ge 0.75~\mu s$, t_{DC} , $t_{DH} \le 0.35~\mu s$
 - ① CL: Normal high

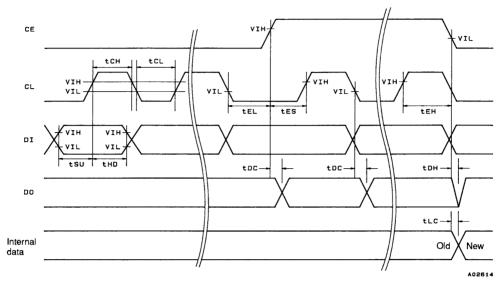


@ CL: Normal low

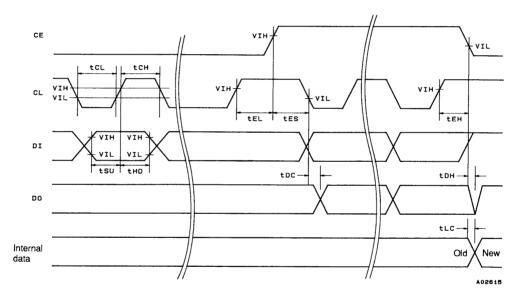


Note: Since the DO pin is an n-channel open drain pin, the time for the data to change (t_{DC} and t_{DH}) will differ depending on the value of the pull-up resistor and printed circuit board capacitance.

7. Serial Data Timing



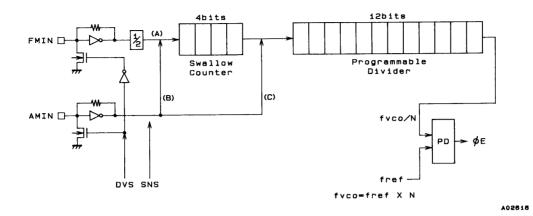
When stopped with CL low



When stopped with CL high

Parameter	Symbol	Pins	Conditions	min	typ	max	Unit
Data setup time	t _{SU}	DI, CL		0.75			μs
Data hold time	t _{HD}	DI, CL		0.75			μs
Clock low-level time	t _{CL}	CL		0.75			μs
Clock high-level time	t _{CH}	CL		0.75			μs
CE wait time	t _{EL}	CE, CL		0.75			μs
CE setup time	t _{ES}	CE, CL		0.75			μs
CE hold time	t _{EH}	CE, CL		0.75			μs
Data latch change time	t _{LC}					0.75	μs
Data output time	t _{DC}	DO, CL	Differs depending on the value of the pull-up resistor			0.35	
Data output time	t _{DH}	DO, CE	and the printed circuit board capacitance.			0.35	μs

Programmable Divider



	DVS	SNS	Input pin	Set divisor	Actual divisor: N	Input frequency range (MHz)
Α	1	*	FMIN	272 to 65535	Twice the set value	10 to 160
В	0	1	AMIN	272 to 65535	The set value	2 to 40
С	0	0	AMIN	4 to 4095	The set value	0.5 to 10

Note: * Don't care.

- 1. Programmable Divider Calculation Examples
 - FM, 50 kHz steps (DVS = 1, SNS = *, FMIN selected)

FM RF = 90.0 MHz (IF = +10.7 MHz)

FM VCO = 100.7 MHz

PLL fref = 25 kHz (R0 to R1 = 1, R2 to R3 = 0)

100.7 MHz (FM VCO) \div 25 kHz (fref) \div 2 (FMIN: divide-by-two prescaler) = 2014 \rightarrow 07DE (HEX)

,		E D						7 0																
ĺ	0	1	1	1	1	0	1	1	4	1	1	0	0	0	0	0	*	1			1	1	0	0
	ЬО	P1	P2	ьз	P4	P5	P6	P7	84	99	P10	P11	P12	P13	P14	P15	888	s A O	CTE	xs	ВО	R1	R2	нз

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• SW, 5 kHz steps (DVS = 0, SNS = 1, AMIN high speed side selected)

SW RF = 21.75 MHz (IF = +450 kHz)

SW VCO = 22.20 MHz

PLL fref = 5 kHz (R0 = R2 = 0, R1 = R3 = 1)

22.2 MHz (SW VCO) \div 5 kHz (fref) = 4440 \rightarrow 1158 (HEX)

_	5	_	_	_	5	<u> </u>	_	_	_;		_	_		<u>_</u>									
0	0	0	1	1	0	1	0	1	0	0	0	1	0	0	0	1	0			0	1	0	1
90	14	P2	РЗ	P.4	P5	96	7 d	8 d	P9	P10	P11	P15	P13	P14	P15	SNS	SAO	CTE	xs.	B0	P.	R2	В3

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• MW, 10 kHz steps (DVS = 0, SNS = 0, AMIN low-speed side selected)

MW RF = 1000 kHz (IF = +450 kHz)

MW VCO = 1450 kHz

PLL fref = 10 kHz (R0 to R2 = 0, R3 = 1)

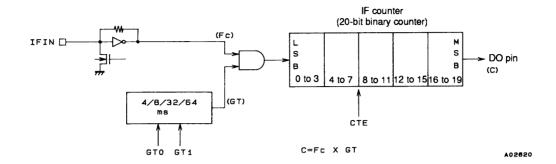
1450 kHz (MW VCO) \div 10 kHz (fref) = 145 \rightarrow 091 (HEX)

				_		_	_	_	ز			_		<u>_</u>									
*	*	*	*	1	0	0	0	1	0	0	1	0	0	0	0	0	0			0	0	0	1
Ь	P.1	P2	ьз	P.4	PS	PG	Р7	8 d	9 6 4	P10	P11	P12	P13	P14	P15	SNS	SAO	CTE	sx	80	18	H2	ВЗ

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IF Counter

The LC72130 IF counter is a 20-bit binary counter. The result, i.e., the counter's msb, can be read serially from the DO pin.



GT1	GT0	Measurement time									
GII	Gio	Measurement period (GT) (ms)	Wait time (twu) (ms)								
0	0	4	3 to 4								
0	1	8	3 to 4								
1	0	32	7 to 8								
1	1	64	7 to 8								

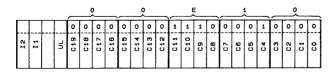
The IF frequency (Fc) is measured by determining how many pulses were input to an IF counter in a specified measurement period, GT.

$$Fc = \frac{C}{GT}$$
 (C = Fc × GT) C: Count value (number of pulses)

- 1. IF Counter Frequency Calculation Examples
 - When the measurement period (GT) is 32 ms, the count (C) is 53980 hexadecimal (342400 decimal): IF frequency (Fc) = $342400 \div 32$ ms = 10.7 MHz

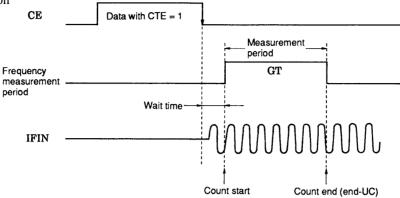
			5								9			,B									
			0	1	0	1	0	0	1	1	1	0	0	1	1	0	0	0	0	0	0	0	l
12	11	٦n	C19	C18	C17	C16	C15	C14	C13	C12	C11	C10	60	80	ZÓ	90	90	6.4	63	CS	C1	00	
																						AO	26

• When the measurement period (GT) is 8 ms, the count (C) is E10 hexadecimal (3600 decimal): IF frequency (Fc) = $3600 \div 8 \text{ ms} = 450 \text{ kHz}$



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2. IF Counter Operation



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Prior to starting the IF counter, reset the IF counter in advance by setting CTE in the serial data to zero.

The IF counter is started by changing the value of CTE in the serial data from zero to one. The serial data is latched when the CE pin is dropped from high to low. The IF signal must be supplied to the IFIN pin in the period between the point the CE pin goes low and the end of the wait time at the latest. Next, the value of the IF counter at the end of the measurement period must be read out during the period that CTE is 1. This is because the IF counter is reset when CTE is set to 0.

Note: When operating the IF counter, the control microprocessor must check for the presence of the IF-IC SD (station detect signal) and, must turn on the IF buffer output and operate the counter only if the SD signal is present. Autosearch techniques that use only the IF counter are not recommended, since it is possible for IF buffer leakage output to cause incorrect stops at points where there is no station.

IFIN minimum input sensitivity standard

f (MHz)

IFS	0.4 ≤ f < 0.5	0.5 ≤ f < 8	8 ≤ f ≤ 12
1: Normal mode	40 mVrms (0.1 to 3 mVrms)	40 mVrms	40 mVrms (1 to 10 mVrms)
0: Degradation mode	70 mVrms (10 to 15 mVrms)	70 mVrms	70 mVrms (30 to 40 mVrms)

(): Actual values (reference data)

Unlock Detection Timing

1. Unlock Detection Determination Timing

Unlocked state detection is performed in the reference frequency (fref) period (interval). Therefore, in principle, this determination must be performed over a period no less than the reference frequency period. However, directly following a change to the (frequency) divisor N, that determination must be performed after at least two reference frequency periods have passed.

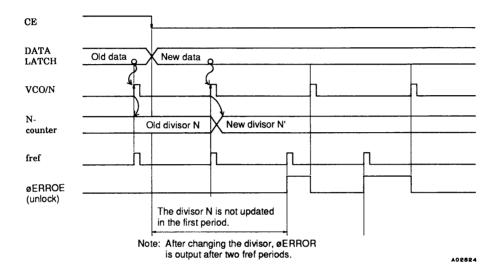


Figure 1 Unlocked State Detection Timing

For example, if fref is 1 kHz, i.e., the period is 1 ms, after the divisor N is changed, unlocked state determination must be performed after waiting 2 ms.

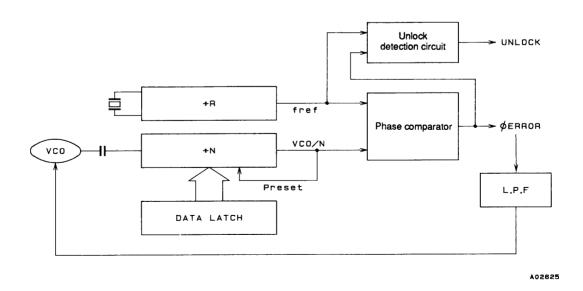
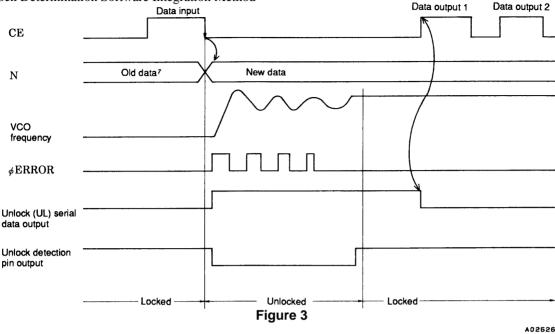


Figure 2 Circuit Structure

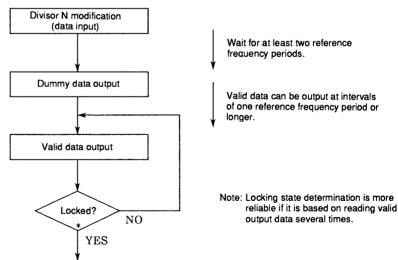
2. Unlock Determination Software Integration Method



3. Unlocked State Data Output Using Serial Data Output

In the LC72130, once an unlocked state occurs, the unlocked state serial data (UL) will not be reset until a data input (or output) operation is performed. At the data output 1 point in Figure 3, although the VCO frequency has stabilized (locked), since no data output has been performed since the divisor N was changed the unlocked state data remains in the unlocked state. As a result, even though the frequency has stabilized (locked), the system remains (from the standpoint of the data) in the unlocked state.

Therefore, the unlocked state data acquired at data output 1, which occurs immediately after the divisor N was changed, should be treated as a dummy data output and ignored. The second data output (data output 2) and following outputs are valid data.



Locked State Determination Flowchart

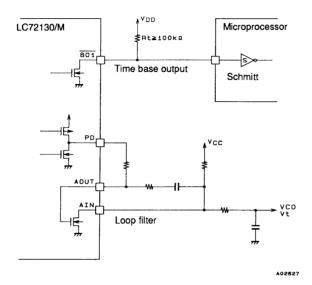
4. Directly Outputting Unlocked State Data from the DO Pin (Set by the DO pin control data)

Since the locking state (high = locked, low = unlocked) is output directly from the DO pin, the dummy data processing described in section 3 above is not required. After changing the divisor N, the locking state can be checked after waiting at least two reference frequency periods.

Clock Time Base Usage Notes

The pull-up resistor used on the clock time base output pin $(\overline{BO1})$ should be at least 100 k Ω . Also, to prevent chattering we recommend using a Schmitt input at the controller (microprocessor) that receives this signal.

This is to prevent degrading the VCO C/N characteristics when a loop filter is formed using the built-in low-pass filter transistor. Since the clock time base output pin and the low-pass filter have a common ground internal to the IC, it is necessary to minimize the time base output pin current fluctuations and to suppress their influence on the low-pass filter.



Other Items

1. Notes on the Phase Comparator Dead Zone

DZ1	DZ0	Dead zone mode	Charge pump	Dead zone				
0	0	DZA	ON/ON	0 s				
0	1	DZB	ON/ON	−0 s				
1	0	DZC	OFF/OFF	+0 s				
1	1	DZD	OFF/OFF	+ +0 s				

Since correction pulses are output from the charge pump even if the PLL is locked when the charge pump is in the ON/ON state, the loop can easily become unstable. This point requires special care when designing application circuits.

The following problems may occur in the ON/ON state.

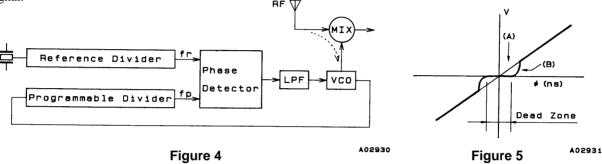
- Side band generation due to reference frequency leakage
- Side band generation due to both the correction pulse envelope and low frequency leakage

Schemes in which a dead zone is present (OFF/OFF) have good loop stability, but have the problem that acquiring a high C/N ratio can be difficult. On the other hand, although it is easy to acquire a high C/N ratio with schemes in which there is no dead zone, it is difficult to achieve high loop stability. Therefore, it can be effective to select DZA or DZB, which have no dead zone, in applications which require an FM S/R ratio in excess of 90 to 100 dB, or in which an increased AM stereo pilot margin is desired. On the other hand, we recommend selecting DZC or DZD, which provide a dead zone, for applications which do not require such a high FM signal-to-noise ratio and in which either AM stereo is not used or an adequate AM stereo pilot margin can be achieved.

Dead Zone

The phase comparator compares fp to a reference frequency (fr) as shown in Figure 4. Although the characteristics of this circuit (see Figure 5) are such that the output voltage is proportional to the phase difference \emptyset (line A), a region (the dead zone) in which it is not possible to compare small phase differences occurs in actual ICs due to internal circuit delays and other factors (line B). A dead zone as small as possible is desirable for products that must provide a high S/N ratio.

However, since a larger dead zone makes this circuit easier to use, a larger dead zone is appropriate for popularly-priced products. This is because it is possible for RF signals to leak from the mixer to the VCO and modulate the VCO in popularly-priced products in the presence of strong RF inputs. When the dead zone is narrow, the circuit outputs correction pulses and this output can further modulate the VCO and generate beat frequencies with the RF signal.



2. Notes on the FMIN, AMIN, and IFIN Pins

Coupling capacitors must be placed as close as possible to their respective pin. A capacitance of about 100 pF is desirable. In particular, if a capacitance of 1000 pF or over is used for the IF pin, the time to reach the bias level will increase and incorrect counting may occur due to the relationship with the wait time.

3. Notes on IF Counting → SD must be used in conjunction with the IF counting time When using IF counting, always implement IF counting by having the microprocessor determine the presence of the IF-IC SD (station detect) signal and turn on the IF counter buffer only if the SD signal is present. Schemes in which auto-searches are performed with only IF counting are not recommended, since they can stop at points where there is no signal due to leakage output from the IF counter buffer.

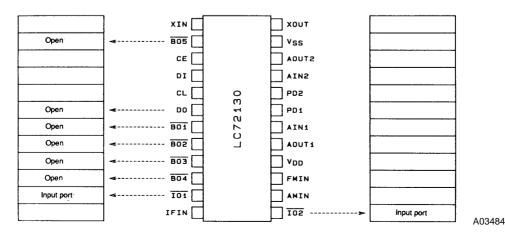
4. DO Pin Usage Techniques

In addition to data output mode times, the DO pin can also be used to check for IF counter count completion and for unlock detection output. Also, an input pin state can be output unchanged through the DO pin and input to the controller.

5. Power Supply Pins

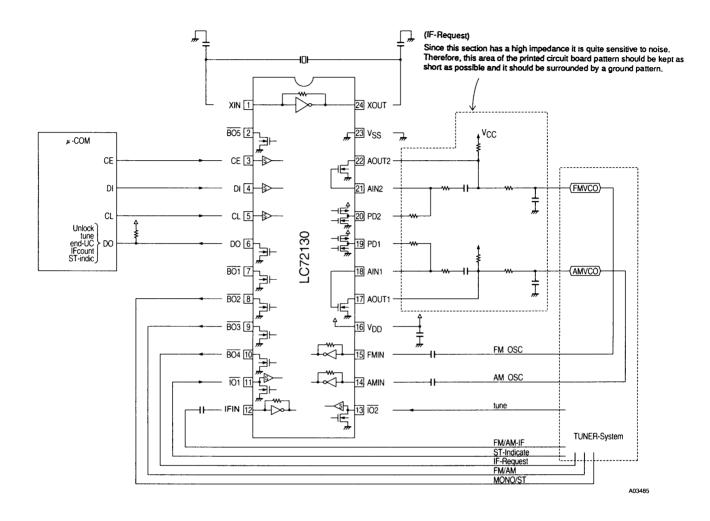
A capacitor of at least 2000 pF must be inserted between the power supply V_{DD} and V_{SS} pins for noise exclusion. This capacitor must be placed as close as possible to the V_{DD} and V_{SS} pins.

Pin States After the Power ON Reset



No. 4973-21/22

Sample Application System



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